

MOS FIELD EFFECT TRANSISTOR

2SK3435

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3435 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

• Super low on-state resistance:

RDS(on)1 = $14 \text{ m}\Omega$ MAX. (VGS = 10 V, ID = 40 A)

- ★ RDS(on)2 = 22 m Ω MAX. (Vgs = 4.0 V, ID = 40 A)
- ★ Low Ciss: Ciss = 3200 pF TYP.
 - Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

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V	/
Α	4
Α	4
V	٧
V	٧
°(С
°(С
Α	4
m	าป
	\ 0

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting T_{ch} = 25 °C, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

10.00 11 1 11 = 10 pts, 2 atty 6/6.6 = 1 76

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3435	TO-220AB
2SK3435-S	TO-262
2SK3435-Z	TO-220SMD

(TO-220AB)



(TO-262)



(TO-220SMD)



THERMAL RESISTANCE

★ Cha	Channel to Case	Rth(ch-C)	1.49	°C/W
	Channel to Ambient	Rth(ch-A)	83.3	°C/W

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

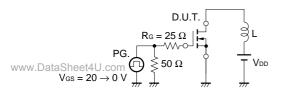
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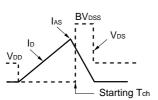


ELECTRICAL CHARACTERISTICS (TA = 25 °C)

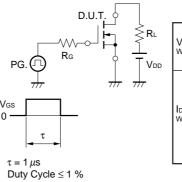
	CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 40 A		11	14	mΩ
*		RDS(on)2	Vgs = 4.0 V, ID = 40 A		16	22	mΩ
	Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
*	Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 40 A	21	43		S
	Drain Leakage Current	Idss	V _{DS} = 60 V, V _{GS} = 0 V			10	μΑ
	Gate to Source Leakage Current	lgss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
*	Input Capacitance	Ciss	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		3200		pF
	Output Capacitance	Coss			520		pF
	Reverse Transfer Capacitance	Crss			260		pF
	Turn-on Delay Time	td(on)	$I_D = 40 \text{ A}, V_{GS(on)} = 10 \text{ V}, V_{DD} = 30 \text{ V},$		80		ns
*	Rise Time	tr	$R_G = 10 \Omega$		1200		ns
	Turn-off Delay Time	td(off)			200		ns
	Fall Time	tf			350		ns
*	Total Gate Charge	Q _G	ID = 80 A , VDD = 48 V, VGS = 10 V		60		nC
*	Gate to Source Charge	Qgs			10		nC
*	Gate to Drain Charge	Q _{GD}			16		nC
	Body Diode Forward Voltage	V _{F(S-D)}	IF = 80 A, VGS = 0 V		1.0		V
*	Reverse Recovery Time	trr	IF = 80 A, VGS = 0 V,		46		ns
*	Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		66		nC

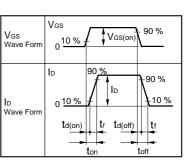
TEST CIRCUIT 1 AVALANCHE CAPABILITY





TEST CIRCUIT 2 SWITCHING TIME

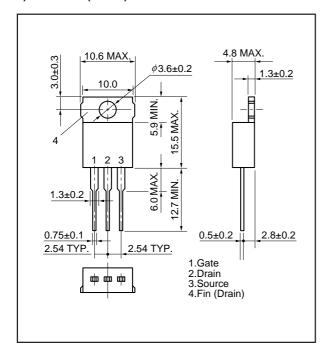




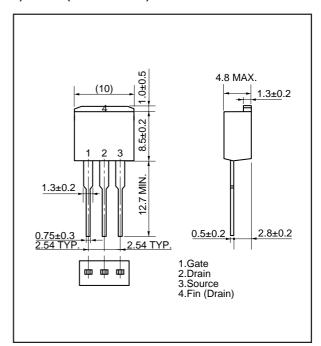
TEST CIRCUIT 3 GATE CHARGE

PACKAGE DRAWINGS (Unit: mm)

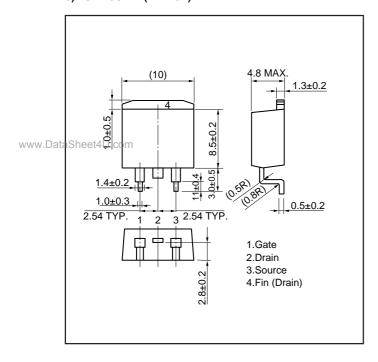
1) TO-220AB (MP-25)



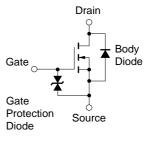
2) TO-262 (MP-25 Fin Cut)



3) TO-220SMD (MP-25Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

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